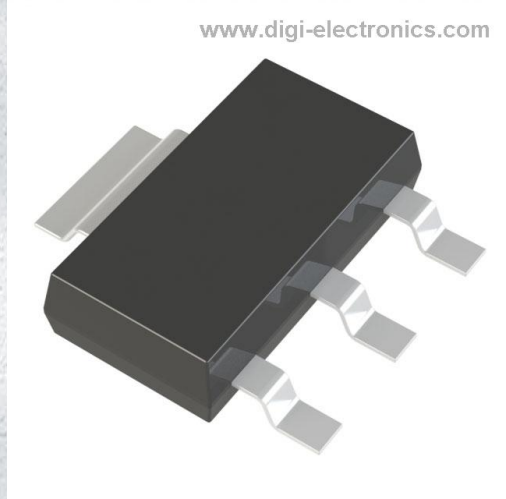
FZT1051ATA Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number	FZT1051ATA-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	FZT1051ATA
Description	TRANS NPN 40V 5A SOT223-3
Detailed Description	Bipolar (BJT) Transistor NPN 40 V 5 A 155MHz 2.5 W Surface Mount SOT-223-3

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
FZT1051ATA	Diodes Incorporated
Series:	Product Status:
-	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	5 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ Ib, Ic:
40 V	340mV @ 100mA, 5A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
10nA	270 @ 1A, 2V
Power - Max:	Frequency - Transition:
2.5 W	155MHz
Operating Temperature:	Mounting Type:
-55°C ~ 150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
TO-261-4, TO-261AA	SOT-223-3
Base Product Number:	
FZT1051	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	
8541.29.0075	

Green

FZT1051A

40V NPN MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > 40V
- I_C = 5A High Continuous Collector Current
- I_{CM} = 20A Peak Pulse Current
- Low Saturation Voltage $V_{CE(sat)}$ < 120mV @ 1A
- R_{SAT} = 50mΩ @ 5A for a Low Equivalent On-Resistance
- h_{FE} Specified up to 10A for a High Gain Hold-Up
- Complementary PNP Type: FZT1151A
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/**

Mechanical Data

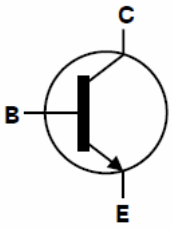
- Package: SOT223 (Type DN)
- Package Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.112 grams (Approximate)

Applications

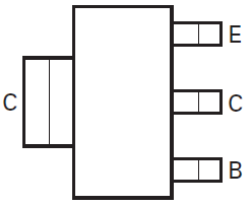
- Solenoid, relay, and actuator drivers
- DC modules
- Motor controls

SOT223 (Type DN)

Top View



Device Symbol



Top View
Pin-Out

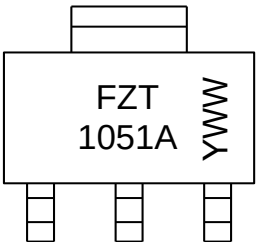
Ordering Information (Note 4)

Orderable Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
				Quantity	Carrier
FZT1051ATA	FZT1051A	7	12	1,000	Reel
FZT1051ATC	FZT1051A	13	12	4,000	Reel

Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT223



FZT 1051A = Product Type Marking Code
YWW = Date Code Marking
Y or $\overline{Y}$ = Last Digit of Year (ex: 4 = 2024)
WW or $\overline{WW}$ = Week Code (01 to 53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	150	V
Collector-Emitter Voltage	V_{CEO}	40	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	I_C	5	A
Peak Pulse Current	I_{CM}	20	A
Base Current	I_B	1	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	3.0	W
	(Note 6)		2.0	
	(Note 7)		1.6	
	(Note 8)		1.2	
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	41.7	°C/W
	(Note 6)		62.5	
	(Note 7)		78.1	
	(Note 8)		104	
Thermal Resistance Junction to Lead	(Note 9)	$R_{\theta JL}$	10.9	
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

Notes:
5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
7. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
8. Same as Note 5, except the device is mounted on minimum recommended pad layout.
9. Thermal resistance from junction to solder-point (at the end of the collector lead).
10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

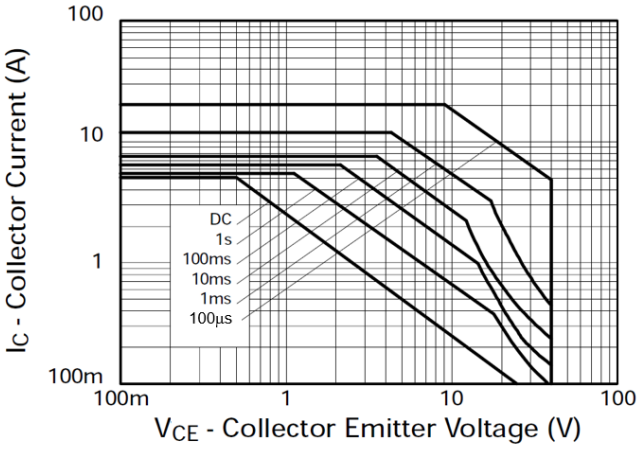


Fig.1 Safe Operating Area

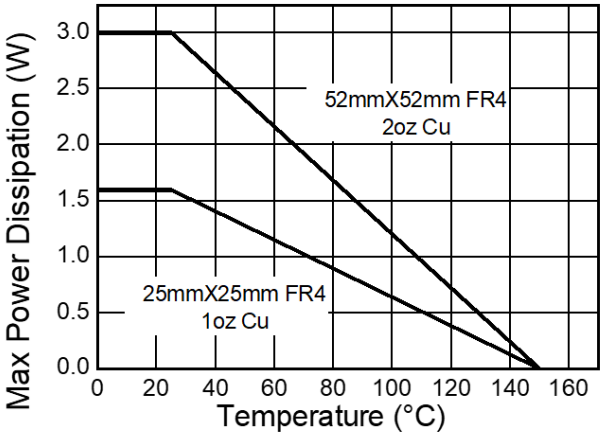


Fig.2 Derating Curve

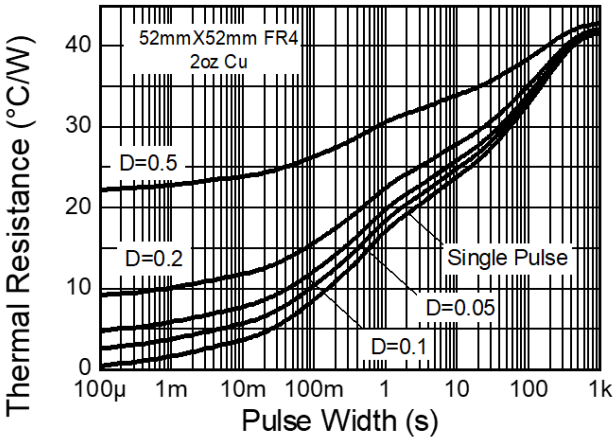


Fig.3 Transient Thermal Impedance

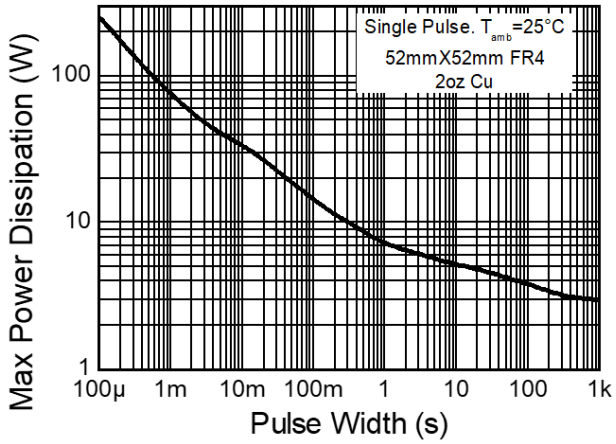


Fig.4 Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	150	190	—	V	I_C = 100µA
Collector-Emitter Breakdown Voltage	BV_{CES}	150	190	—	V	I_C = 100µA
Collector-Emitter Breakdown Voltage	BV_{CEV}	150	190	—	V	I_C = 100µA, V_{EB} = 1V
Collector-Emitter Breakdown Voltage (Note 11)	BV_{CEO}	40	60	—	V	I_C = 10mA
Emitter-Base Breakdown Voltage	BV_{EBO}	7	8.1	—	V	I_E = 100µA
Collector Cut-Off Current	I_{CBO}	— —	<1 —	10 0.5	nA µA	V_{CB} = 120V V_{CB} = 120V, T_A = +100°C
Collector Cut-Off Current	I_{CES}	—	<1	10	nA	V_{CB} = 120V
Emitter Cut-Off Current	I_{EBO}	—	<1	10	nA	V_{EB} = 6V
Collector-Emitter Saturation Voltage (Note 11)	$V_{CE(sat)}$	—	17	25	mV	I_C = 200mA, I_B = 10mA
		—	85	120		I_C = 1A, I_B = 10mA
		—	140	180		I_C = 2A, I_B = 20mA
		—	250	340		I_C = 5A, I_B = 100mA
Base-Emitter Saturation Voltage (Note 11)	$V_{BE(sat)}$	—	980	1100	mV	I_C = 5A, I_B = 100mA
Base-Emitter Turn-On Voltage (Note 11)	$V_{BE(on)}$	—	915	1000	mV	I_C = 5A, V_{CE} = 2V
DC Current Gain (Note 11)	h_{FE}	290	440	—	—	I_C = 10mA, V_{CE} = 2V
		270	450	1200		I_C = 1A, V_{CE} = 2V
		130	220	—		I_C = 5A, V_{CE} = 2V
		40	55	—		I_C = 10A, V_{CE} = 2V
Output Capacitance	C_{obo}	—	27	40	pF	V_{CB} = 10V, f = 1MHz
Current Gain-Bandwidth Product	f_T	—	155	—	MHz	V_{CE} = 10V, I_C = 50mA, f = 100MHz
Switching Times	t_{on}	—	220	—	ns	I_C = 3A, V_{CC} = 10V, I_{B1} = -I_{B2} = 30mA
	t_{off}	—	540	—		

Note: 11. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

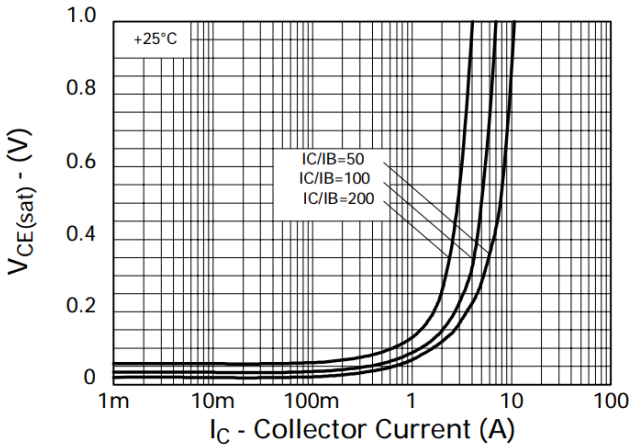


Fig.5 $V_{CE(sat)}$ v I_C

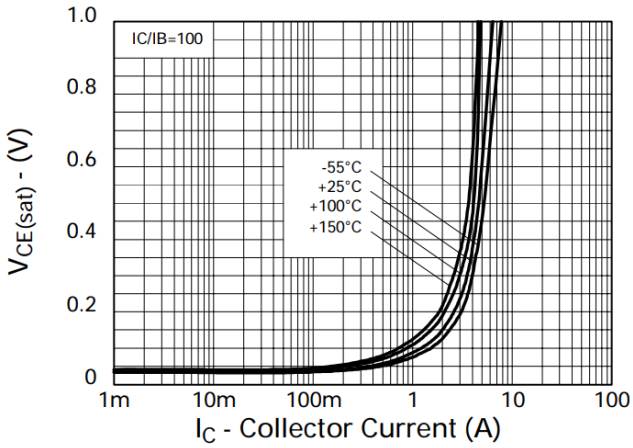


Fig.6 $V_{CE(sat)}$ v I_C

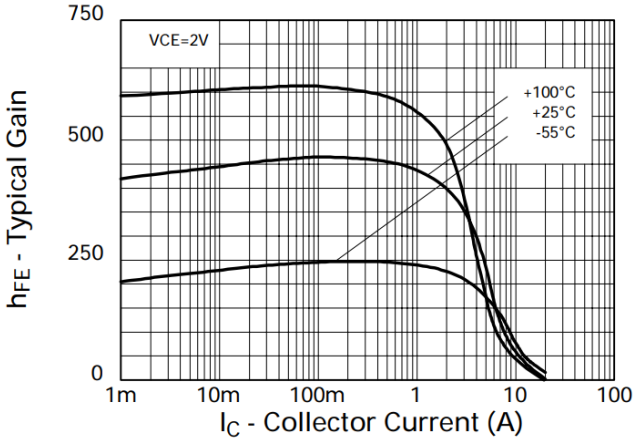


Fig.7 h_{FE} v I_C

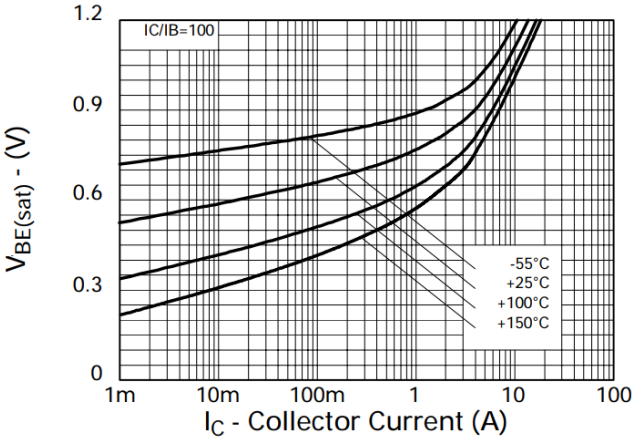


Fig.8 $V_{BE(sat)}$ v I_C

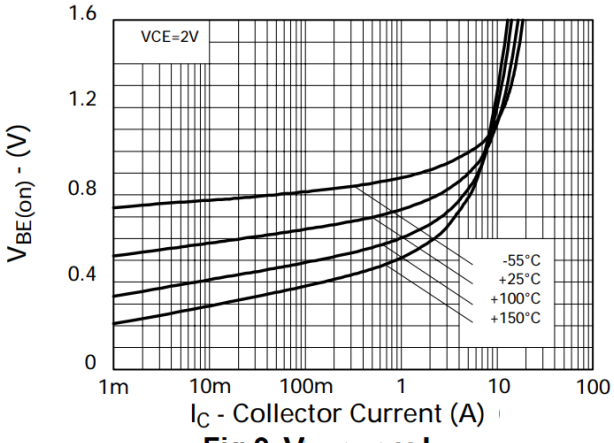
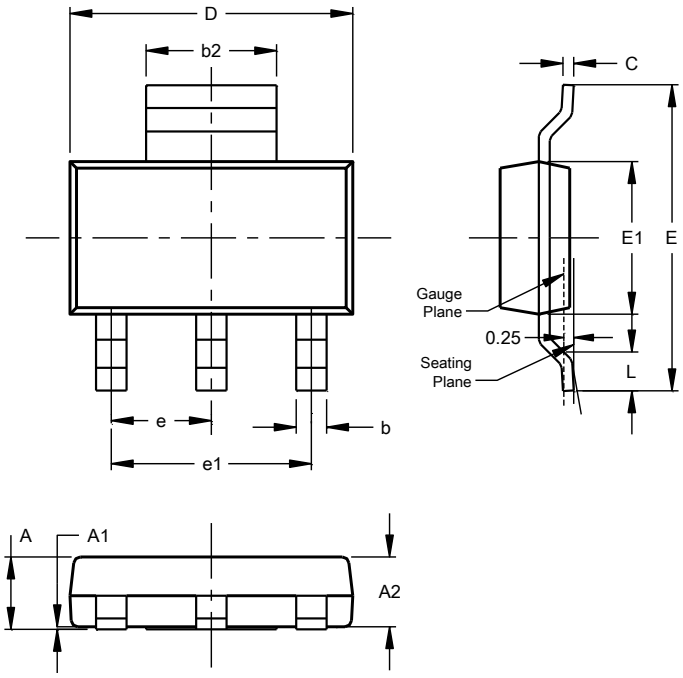


Fig.9 $V_{BE(on)}$ v I_C

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

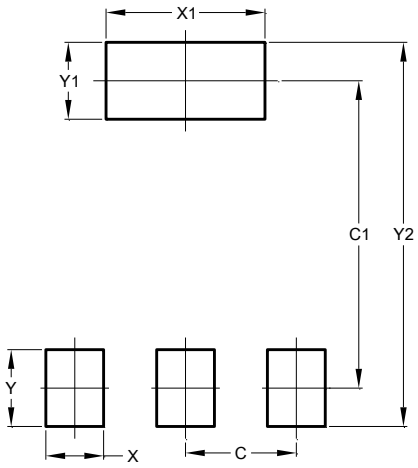


SOT223 (Type DN)			
Dim	**Min**	**Max**	**Typ**
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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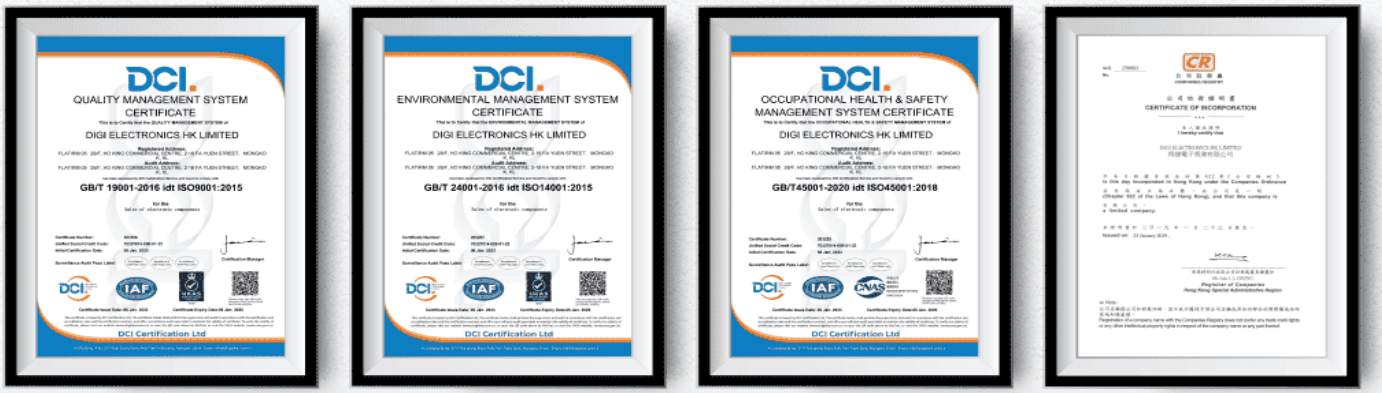

Tel: +00 852-30501935

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